

International
IR Rectifier

SAFEIR Series
40TPS16

PHASE CONTROL SCR

	$V_T < 1.45V @ 40A$
	$I_{TSM} = 500A$
	$V_{RRM} = 1600V$

Description/Features

The 40TPS16 **SAFEIR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125°C junction temperature. Low lgt parts available.

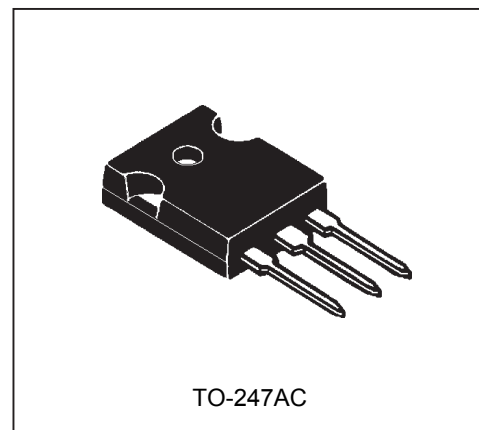
Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

Major Ratings and Characteristics

Characteristics	40TPS16	Units
$I_{T(AV)}$ Sinusoidal waveform	35	A
I_{RMS}	55	A
V_{RRM}/V_{DRM} Range (*)	1600	V
I_{TSM}	500	A
$V_T @ 40A, T_J = 25^\circ C$	1.45	V
dv/dt	1000	V/ μs
di/dt	100	A/ μs
T_J	-40 to 125	$^\circ C$

(*) Contact Factory

Package Outline



Voltage Ratings

Part Number	V_{RRM}/V_{DRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM}/I_{DRM} 125°C mA
40TPS16	1600	1700	10

Absolute Maximum Ratings

Parameters		40TPS16	Units	Conditions	
I _{T(AV)}	Max. Average On-state Current		35	A @ T _C = 79° C, 180° conduction half sine wave	
I _{T(RMS)}	Max. Continuous RMS On-state Current As AC switch	55			
I _{TSM}	Max. Peak One Cycle Non-Repetitive Surge Current	500	A	10ms Sine pulse, rated V _{RRM} applied	Initial T _J = T _J max.
		600		10ms Sine pulse, no voltage reapplied	
I ² t	Max. I ² t for Fusing	1250	A ² s	10ms Sine pulse, rated V _{RRM} applied	
		1760		10ms Sine pulse, no voltage reapplied	
I ² √t	Max. I ² √t for Fusing	12500	A ² √s	t = 0.1 to 10ms, no voltage reapplied	
V _{T(TO)1}	Low Level Value of Threshold Voltage	1.02	V	T _J = 125°C	
V _{T(TO)2}	High Level Value of Threshold Voltage	1.23			
r _{t1}	Low Level Value of On-state Slope Resistance	9.74			
r _{t2}	High Level Value of On-state Slope Resistance	7.50	mΩ		
V _{TM}	Max. Peak On-state Voltage	1.85	V	@ 110A, T _J = 25°C	
di/dt	Max. Rate of Rise of Turned-on Current	100	A/μs	T _J = 25°C	
I _H	Max. Holding Current	150	mA		
I _L	Max. Latching Current	300			
I _{RRM} /I _{DRM}	Max. Reverse and Direct Leakage Current	0.5 10			
			T _J = 25°C	V _R = rated V _{RRM} / V _{DRM}	
			T _J = 125°C		
dv/dt	Max. Rate of Rise of Off-state Voltage	1000	V/μs	T _J = T _J max., linear to 80% V _{DRM} , R _g -k = open	

Triggering

Parameters		40TPS16	Units	Conditions	
P _{GM}	Max. peak Gate Power	10	W		
P _{G(AV)}	Max. average Gate Power	2.5			
I _{GM}	Max. peak Gate Current	2.5	A		
- V _{GM}	Max. peak negative Gate Voltage	10	V		
V _{GT}	Max. required DC Gate Voltage to trigger	4.0		T _J = - 40°C	Anode supply = 6V resistive load
		2.5		T _J = 25°C	
		1.7		T _J = 125°C	
I _{GT}	Max. required DC Gate Current to trigger	270	mA	T _J = - 40°C	
		150		T _J = 25°C	
		80		T _J = 125°C	
		40		T _J = 25°C, for 40TPS08A	
V _{GD}	Max. DC Gate Voltage not to trigger	0.25	V	T _J = 125°C, V _{DRM} = rated value	
I _{GD}	Max. DC Gate Current not to trigger	6	mA		

Thermal-Mechanical Specifications

Parameters		40TPS16	Units	Conditions
T _J	Max. Junction Temperature Range	- 40 to 125	°C	
T _{stg}	Max. Storage Temperature Range	- 40 to 125		
R _{thJC}	Max. Thermal Resistance Junction to Case	0.6	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	40		
R _{thCS}	Max. Thermal Resistance Case to Heatsink	0.2		Mounting surface, smooth and greased
wt	Approximate Weight		6 (0.21)	g (oz.)
T	Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
		Max.	12 (10)	
Case Style		TO-247AC		

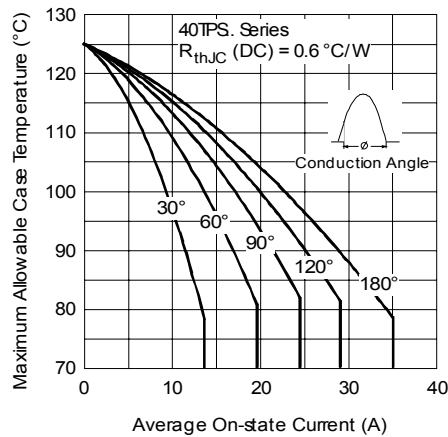


Fig. 1 - Current Rating Characteristics

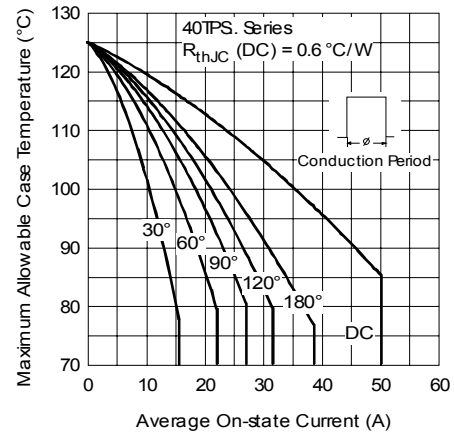


Fig. 2 - Current Rating Characteristics

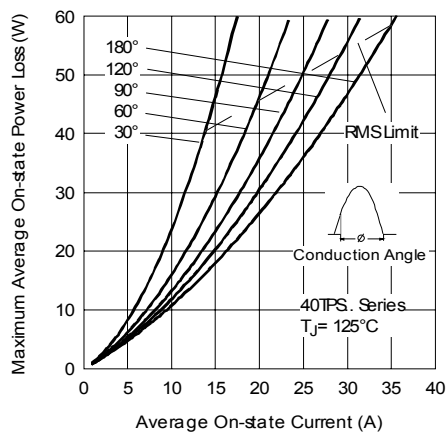


Fig. 3 - On-state Power Loss Characteristics

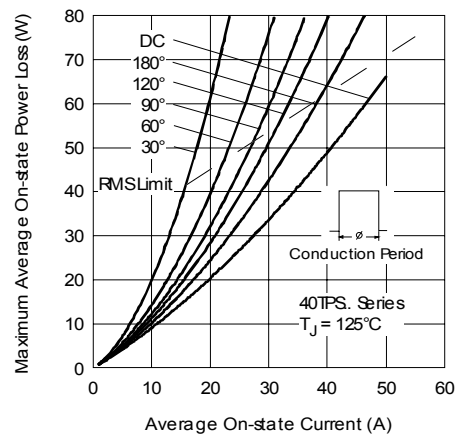


Fig. 4 - On-state Power Loss Characteristics

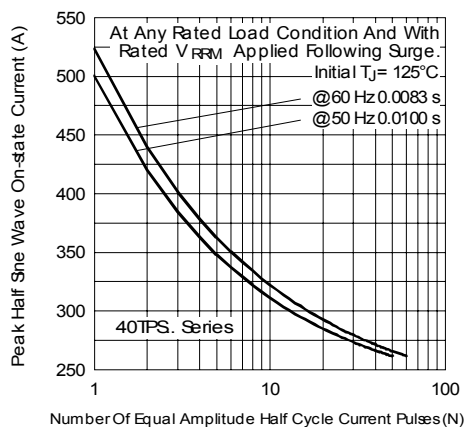


Fig. 5 - Maximum Non-Repulsive Surge Current

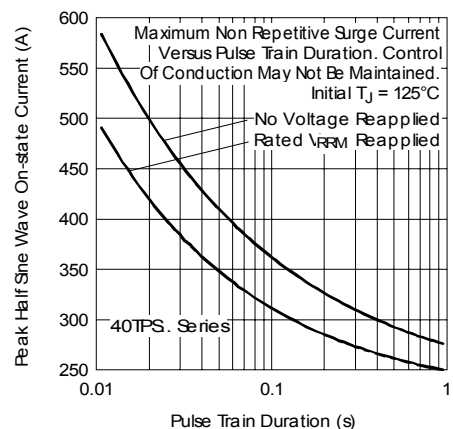


Fig. 6 - Maximum Non-Repulsive Surge Current

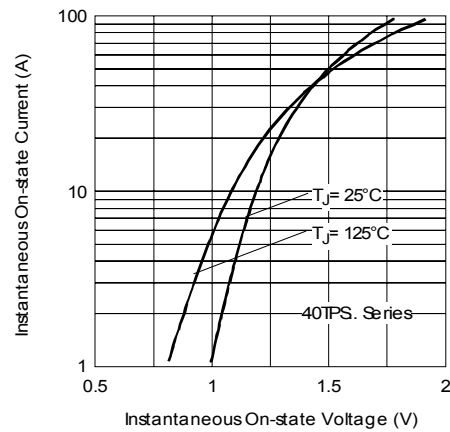


Fig. 7 - On-state Voltage Drop Characteristics

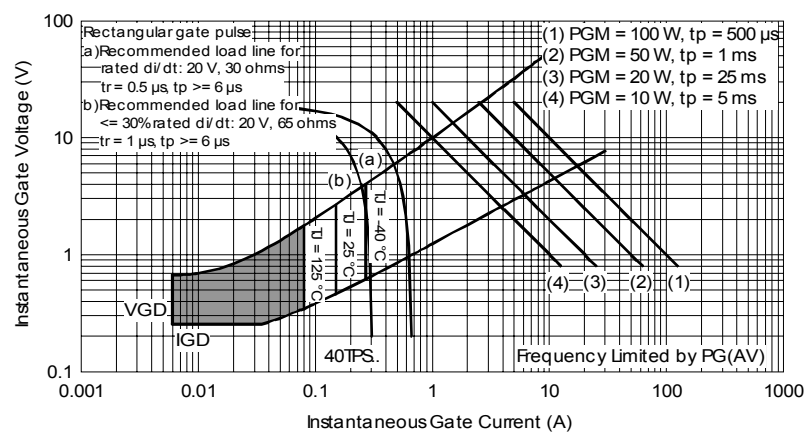


Fig. 8 - Gate Characteristics

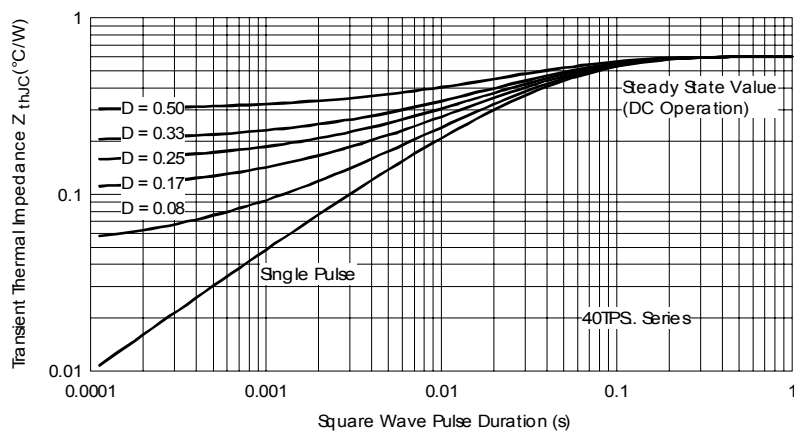


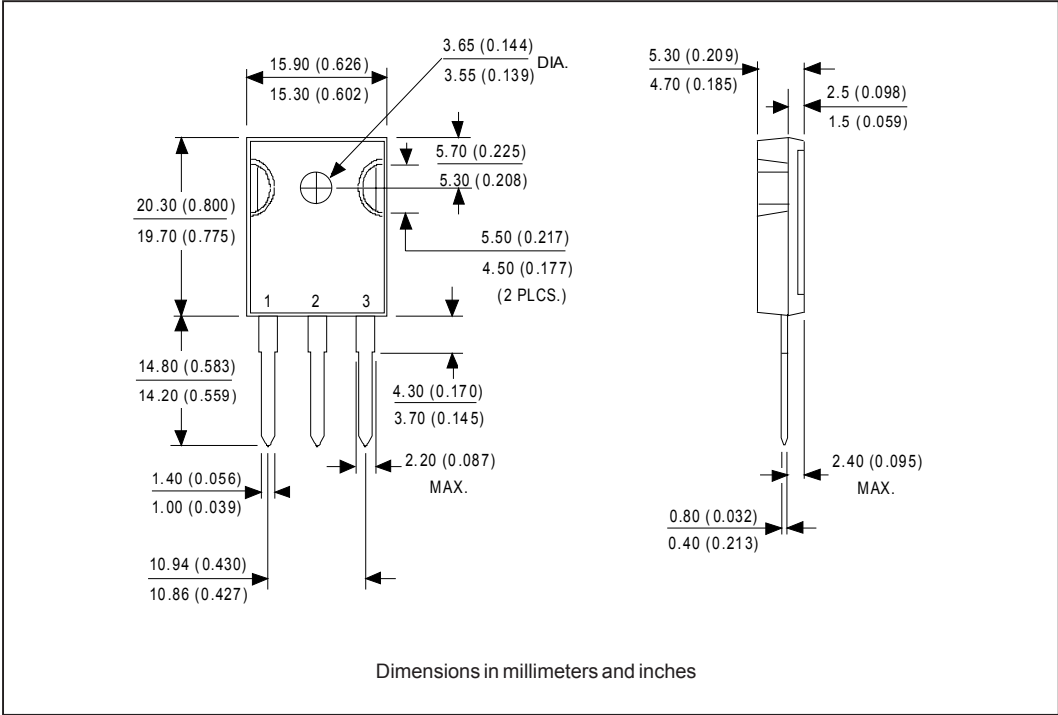
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

40TPS16 *SAFEIR* Series

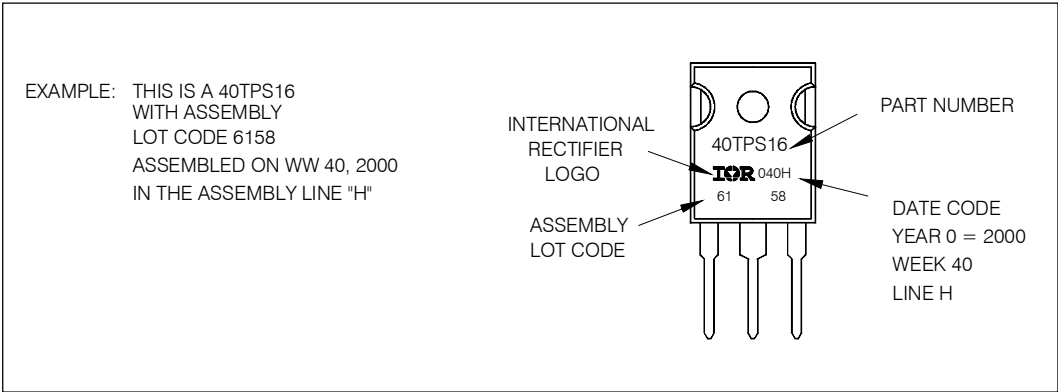
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Outline Table

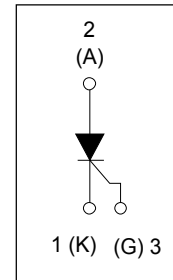


Marking Information



Ordering Information Table

Device Code				
40	T	P	S	16
1	2	3	4	5
1	- Current Rating			
2	- Circuit Configuration:			
	T = Thyristor			
3	- Package:			
	P = TO-247			
4	- Type of Silicon:			
	S = Standard Recovery Rectifier			
5	- Voltage code: Code x 100 = V_{RRM}			
	16 = 1600V (*)			



(*) Contact Factory

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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